

SILICON POWER TRANSISTOR 2SA1412-Z

PNP SILICON TRIPLE DIFFUSED TRANSISTOR

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DESCRIPTION

The 2SA1412-Z is designed for High Voltage Switching, especially in Hybrid Integrated Circuits.

FEATURES

- High Voltage: VcEo = -400 V
- High Speed: $t_f \le 0.7 \mu s$
- · Complement to 2SC3631-Z

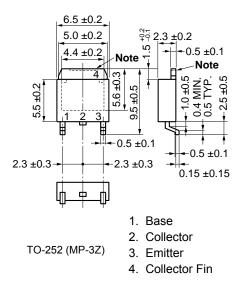
ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Collector to base voltage	Vсво	-400	V
Collector to emitter voltage	VCEO	-400	V
Base to emitter voltage	V_{EBO}	-7	V
Collector current (DC)	Ic(DC)	-2.0	Α
Collector current (pulse) Note 1	I _{C(pulse)}	-4.0	Α
Total power dissipation (T _A = 25°C) Note 2	Рт	2.0	W
Junction temperature	T_{j}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Notes 1. PW \leq 10 ms, Duty Cycle \leq 50%

2. When mounted on ceramic substrate of 7.5 cm $^2 \times 0.7$ mm

PACKAGE DRAWING (Unit: mm)



Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

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ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

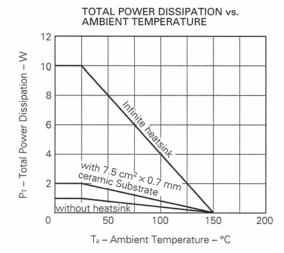
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	Ісво			-10	μΑ	Vcb = -400 V, IE = 0
Emitter Cutoff Current	Ієво			-10	μΑ	VEB = -5.0 V, Ic = 0
DC Current Gain	hFE1*	40	60	120		VcE = -5.0 V, Ic = -0.1 A
DC Current Gain	h _{FE2} *	10	. 22			Vce = -5.0 V, Ic = -1.0 A
Collector Saturation Voltage	VcE(sat)*		-0.25	-0.5	V	Ic = -0.5 A, I _B = -0.1 A
Base Saturation Voltage	V _{BE(sat)} *		-0.85	-1.2	V	Ic = -0.5 A, I _B = -0.1 A
Gain Bandwidth Product	fτ		40		MHz	VcE = -10 V, IE = -100 mA
Output Capacitance	Соь		30		рF	Vсв = −10 V, I∈ = 0, f = 1.0 MHz
Turn-on Time	ton		0.03	0.5	μs	Ic = -1.0 A, R _L = 150 Ω
Storage Time	t stg		1.4	2.0	μs	I _{B1} = −1 _{B2} = −0.2 A,
Fall time	t f		0.1	0.7	μs	Vcc = −150 V

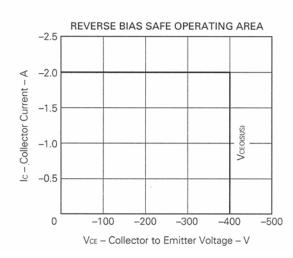
^{*} Pulsed: PW \leq 350 μ s, Duty Cycle \leq 2 %

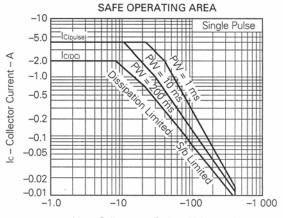
hre Classification

MARKING	L	К	
hFE1	40 to 80	60 to 120	

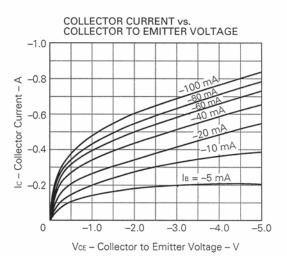
TYPICAL CHARACTERISTICS (Ta = 25 °C)

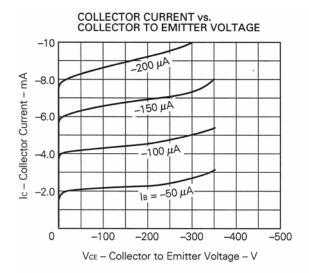




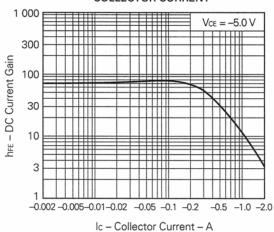


Vce - Collector to Emitter Voltage - V

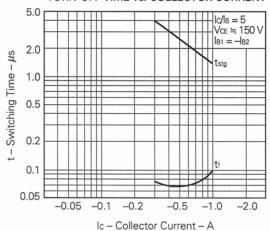




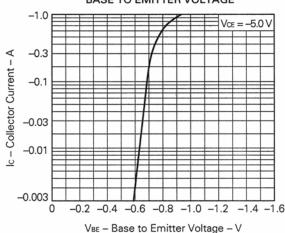




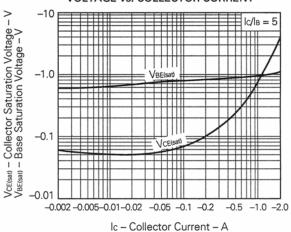
TURN-OFF TIME vs. COLLECTOR CURRENT



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



COLLECTOR AND BASE SATURATION VOLTAGE vs. COLLECTOR CURRENT



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